



Supplementary Materials for

Engineering ligand reactivity enables high-temperature operation of stable perovskite solar cells

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Materials and Methods

Materials

All materials were used as received without further purification. Organic halide salts, including methylammonium iodide (MAI), formamidinium iodide (FAI), methylammonium bromide (MABr) methylammonium chloride (MACl), were purchased from Great Cell Solar, and cesium iodide (CsI) was purchased from Sigma-Aldrich. [2-(9H-Carbazol-9-yl)ethyl]phosphonic Acid (2PACz), lead iodide (PbI₂, 99.99%), and bathocuproine (BCP) were purchased from TCI. Anhydrous solvents including N, N-dimethylformamide (DMF, 99.8%), dimethyl sulfoxide (DMSO, 99.9%), 2-propanol (IPA, 99.5%), chloroform (CF, 99.8%), chlorobenzene (CB, 99.8%), and anisole (99.7%) were purchased from Sigma-Aldrich and toluene (99.8%) was purchased from Alfa Aesar. 3-fluoro-phenethylammonium iodide (3FPEAI) and C₆₀ were purchased from Xi'an Polymer Light Technology Corp. Non-patterned indium tin oxide (ITO) coated glass substrates (15 Ω/sq) were purchased from Tinwell Technology. Commercial patterned ITO substrates (20 Ω/sq) with 25 mm x 25 mm dimensions were purchased from TFD Inc.

Bulky ammonium halide salts, including anilinium iodide (AnI, TCI, 98%), butylammonium iodide (BAI, TCI, 97%), phenethylammonium iodide (PEAI, Great Cell Solar, 99%), were purchased and used as received. 4-fluoroaniline (TCI, 98%), 2,6-difluoroaniline (TCI, 98%), 3,4,5-trifluoroaniline (TCI, 98%), octylamine (Alfa Aesar, 99%), decylamine (Sigma-Aldrich, 95%), and 3,5-di-tert-butylaniline (TCI, 98%) were purchased and converted to ammonium salts using the same procedure as reported before (20). The abbreviations of the converted ammonium salts are 4-fluoroanilinium iodide (4FAnI), 2,6-difluoroanilinium iodide (26FAnI), 3,4,5-trifluoroanilinium iodide (345FAnI), 3,5-di-tert-butylanilinium iodide (35tbuAnI), octylammonium iodide (OAI), and decylammonium iodide (DAI).

Perovskite film fabrication

The precursor solution (1.5 M) was prepared from CsI, MAI, FAI, PbBr₂, and PbI₂ precursors dissolved in mixed solvents of DMF and DMSO with a volume ratio of 4:1. For the Cs_{0.05}MA_{0.15}FA_{0.8}PbI₃ perovskite, the molar ratio for FAI/MAI/CsI was 0.8:0.15:0.05, and 10 mg mL⁻¹ MACl was added in the solution to improve the film morphology; For the Cs_{0.05}MA_{0.05}FA_{0.9}Pb(I_{0.95}Br_{0.05})₃ perovskite, the molar ratios for FAI/MABr/CsI and PbI₂/PbBr₂ were 0.9:0.05:0.05 and 0.95:0.05, respectively. The precursor solution was filtered through a 0.22 μm polytetrafluoroethylene (PTFE) membrane before use. 60 μL of perovskite solution was deposited on the substrate and spun cast at 1000 rpm for 10 s followed by 6000 rpm for 30 s. 150 μL anisole was dropped onto the substrate during the last 5 s of the spinning, resulting in the formation of dark brown films that were then annealed on a hot plate at 100°C for 20 min.

Device fabrication

The pre-patterned ITO or FTO glasses were sequentially sonicated in aqueous detergent, deionized water, acetone, and IPA each for 10 min. After drying with nitrogen, the substrates were exposed to UV-ozone treatment for 15 min to remove organic contaminants. 100 μL of 2PACz in anhydrous ethanol (1 mmol/l) solution was spun-cast at 3000 rpm for 30 s inside the nitrogen-filled glovebox (<0.1 ppm of O_2 and H_2O) and annealed at 100°C for 10 min. Following the 2PACz coating, $\text{Cs}_{0.05}\text{MA}_{0.15}\text{FA}_{0.8}\text{PbI}_3$ perovskites were deposited on the substrate as detailed above. 200 μL of ammonium ligand solution (1mg/mL) in CF with an additional 3% of IPA was then drop cast within 2-3 s on the perovskite film spinning at 4000 rpm (i.e., dynamic spinning) and annealed at 100°C for 5 min. For the exposure time-dependent measurements, 200 μL of ammonium ligand solution was left on the perovskite film for a certain period before spinning at 4000 rpm. Both control and treated films were then transferred to the thermal evaporator (Angstrom engineering), and C_{60} (30 nm) and BCP (7 nm) were deposited sequentially with a rate of 0.3 \AA/s and 0.5 \AA/s , respectively, at a pressure of ca. 2×10^{-6} mbar. Finally, Ag contact (120 nm) was deposited on top of BCP through a shadow mask with the desired aperture area.

For the stability testing, $\text{Cs}_{0.05}\text{MA}_{0.05}\text{FA}_{0.9}\text{Pb}(\text{I}_{0.95}\text{Br}_{0.05})_3$ perovskites were instead deposited as described above, and C_{60} (30 nm) and ALD- SnO_2 were used as the electron transport layer. The deposition of ALD- SnO_2 was carried out in the PICOSUN R-200 Advanced ALD system. H_2O and TDMASn were used as oxygen and tin precursors. Precursor and substrate temperature were set to 75°C and 85°C , respectively. 90 SCCM N_2 was used as carrier gas. Pulse and purge times for H_2O were 1 s and 5 s, and 1.6 s and 5 s for TDMASn . The total deposition cycle is 150, corresponding to 20 nm of SnO_2 .

Module Fabrication

Perovskite solar modules were fabricated on pre-cleaned FTO glass substrates with a size of $6 \times 6 \text{ cm}^2$, which were patterned by a 1030 nm laser (LPKF ProtoLaser R) with nine sub-cells connected in series. FTO substrates were patterned with a laser power of 5 W (P1). The SnO_2 was used as the electron transport layer (ETL) using the chemical bath deposition method. The solution was prepared by adding 2.5 g of urea (Sigma-Aldrich, 99%), 3.5 mL of HCl (Sigma-Aldrich, 37% wt. % in water), 50 μL of thioglycolic acid (Sigma-Aldrich, 98%), and 0.55 g of $\text{SnCl}_2 \cdot 2\text{H}_2\text{O}$ (Sigma-Aldrich, 99.99%) into 200 mL of deionized water. The FTO substrates were immersed into the solution at 90°C for 5 hours, followed by annealing at 190°C for 1 hour. Then 1.5 M perovskite precursors with PbI_2 (TCI America, 99.99%): FAI (GreatCell Solar, 99.99%): MAI (GreatCell Solar, 99.99%): CsI (Sigma-Aldrich, 99.99%): MACl (GreatCell Solar, 99.99%) = 1: 0.85: 0.05: 0.05: 0.20 were dissolved in the mixed DMF (Sigma-Aldrich, 99.8%): DMSO (Sigma-Aldrich, 99.9%) = 4:1 (volume ratio) solvent. The perovskite films were deposited by spin-coating at 1000 rpm for 10 s and 5000 rpm for 30 s. At the 20 s of the second step, 200 μL of chlorobenzene (Sigma-Aldrich, 99.8%) was dropped onto the perovskite films to facilitate crystallization. The perovskite films were annealed at 100°C for 10 min and 150°C for 10 min. The passivation layer was fabricated by spinning 100 μL 345FAn solution (1 mg/mL) in isopropanol (Sigma-Aldrich,

99.5%) and chlorobenzene (1:1 volume ratio) at 5000 rpm 30s, followed by annealing at 100 °C for 10 min. The hole transport layer was deposited by spin-coating 0.06 M spiro-OMeTAD (Sigma-Aldrich, SHT-263 Solarpur) solution in chlorobenzene at 3000 rpm for 20 s. 0.03 M bis(trifluoromethanesulfonyl)-imide lithium salt (Sigma-Aldrich, 99.0%) in acetonitrile (Sigma-Aldrich, 99.8%), 0.2 M 4-tert-Butylpyridine (Sigma-Aldrich, 98%) and 0.0035 M FK 209 Co(III) TFSI salt (GreatCell Solar) in acetonitrile were added to the spiro-OMeTAD solution as additives. Then the P2 lines were patterned aligning with P1 using a laser power of 0.5 W. Finally, the electrode was realized by thermal evaporating a 70 nm gold under high vacuum, followed by P3 etching using a laser power of 0.5 W. The geometric fill factor (GFF) of 92% was defined as the active area (22.0 cm²) divided by the aperture area (23.9 cm²).

Solar cell characterization

The current-voltage (I-V) characteristics of solar cells were measured using a Keithley 2400 sourcemeter under the illumination of solar simulator (Newport, Class AAA) at the light intensity of 100 mW cm⁻² as checked with a calibrated reference solar cell (Newport). Unless otherwise stated, the I-V curves were all measured in a nitrogen atmosphere with a scanning rate of 100 mV s⁻¹ (voltage steps of 10 mV and a delay time of 100 ms). The active area was determined by the aperture shade mask (0.049 cm²) placed in front of the solar cell to avoid overestimation of the photocurrent density. EQE measurements were performed using Newport system (QuantX-300) with monochromatic light and white bias light (~0.2 Sun). The system was calibrated by a certified silicon solar cell.

Stability tests of solar cells

Devices were placed in a homemade stability tracking station. The illumination source is a white light LED with intensity calibrated to match 0.8-sun conditions. For the ISOS-L-3 ageing protocol, the device chamber was left open in a room with 50±10% humidity and solar cell was mounted on a metal plate kept at 85°C by a heating element. A thermal couple attached to the metal plate was used to monitor and provide feedback control to the heating element to ensure temperature consistency. MPP was tracked using a home-build MATLAB-based MPP tracking system using a ‘perturb and observe’ method. The MPP was updated every 1000 minutes. Encapsulation was done by capping the device with a glass slide, using UV-adhesive (Lumtec LT-U001) as a sealant.

AR-XPS measurements

AR-XPS measurements were performed with a Thermo Scientific K-Alpha system with 180° double-focusing, hemispherical analyzer. The system is equipped with a 128-channel detector and monochromated small spot XPS. An Al K α source (1486.6 eV) was used for excitation and a pass energy of 147.6 eV was used for XPS acquisition. Three electron take-off angles ($\alpha = 0^\circ, 45^\circ, \text{ and } 75^\circ$) were defined as the angle between the normal of the perovskite sample and the analyzer (Fig. 1b). Samples mounted on a metal specimen holder were rotated along x, y, z directions to match the analyzing spots. All data were analyzed with Thermo Avantage software.

TR measurements

A regeneratively amplified Yb:KGW laser at a 5 kHz repetition rate (Light Conversion, Pharos) was used to generate femtosecond laser pulses, and a pulse picker was used to lower the frequency to 1 kHz. A portion of the 1,030 nm fundamental was sent into an optical bench (Ultrafast, Helios), where it passed through a retroreflector and was then focused into a calcium fluoride crystal, translated at 1 mm s^{-1} , to create the white light continuum probe. An optical parametric amplifier (Light Conversion, Orpheus) was used to generate the 450 nm pump pulse by upconversion of the fundamental wavelength. This was then sent to the optical bench and was chopped at 500 Hz. Both the pump and probe were sent to the sample, with the time delay adjusted by changing the path length of the probe (time resolution $\sim 350 \text{ fs}$). The probe pulse was then collected by a CCD after dispersion by a grating spectrograph (Ultrafast). Time zero was allowed to vary with wavelength to account for the chirp of the probe.

GIWAXS measurements

GIWAXS measurements were performed at CMS beamline, NSLS II. The monochromatic X-ray with the energy of 13.5 keV shone upon the samples at different grazing incident angles of 0.08° , 0.12° , 0.25° , and 0.5° with an exposure time of 10 s. A Pilatus800K detector was placed 259 mm away from the sample to capture the 2D diffraction pattern.

PL and time-resolved PL (TRPL) measurements

Photoluminescence lifetime (TCSPC) was measured using an Edinburgh Instruments lifspec II fluorescence spectrometer; a picosecond pulse diode laser (EPL-510, excitation wavelength 510 nm, pulse width $< 60 \text{ ps}$, fluence $< 3 \text{ nJ cm}^{-2}$) was used. Absolute intensity photoluminescence spectra were measured using an integrating sphere, and Andor Kymera 193i spectrograph, and a 660 nm continuous-wave laser set at 1-Sun equivalent photon flux ($1.1 \text{ }\mu\text{m}$ beam full-width half-maximum, $632 \text{ }\mu\text{W}$); photoluminescence was collected at normal incidence using a 0.1 NA, $110 \text{ }\mu\text{m}$ -diameter optical fiber.

TOF-SIMS Measurement

The time-of-flight secondary ion mass spectrometry (TOF-SIMS) measurements were performed on the IONTOF M6 instrument with a Bi^{3+} (30 keV) primary ion beam for analysis and an Ar-cluster gun (5 keV) for sputtering due to its low damage depth. Data was acquired for positive ions in an analysis area of $49 \times 49 \text{ }\mu\text{m}^2$ centered inside the cluster raster area of $200 \times 200 \text{ }\mu\text{m}^2$. No distribution gradient was observed for FA cations, indicating that measurement artifacts were successfully minimized (53).

Other characterizations

XRD spectra were collected with a Bruker-AXS D8 advance diffractometer with $\text{Cu K}\alpha$ radiation ($\lambda = 1.5418 \text{ \AA}$) operating at 40 kV and 40 mA. Contact angles were measured with a standard

goniometer (Ramé-hart) equipped with a camera was used to measure. A 4 μl drop of deionized water was placed onto the target surface and pictures were captured after 2 s of depositing the drop. The images were analyzed using ImageJ software to extract macroscale contact angle data. UPS measurements were taken with an Excitech H Lyman- α photon source (10.2 eV) with an oxygen-filled beam path coupled with the same PHI 5600 UHV and analyzer system. A sample bias of -5 V was applied and a pass energy of 5.85 eV was used for UPS acquisition. High-resolution SEM images were obtained using the Hitachi S5200 microscope with an accelerating voltage of 1.5 kV. A low accelerating voltage and a low beam current were deployed to reduce surface damage of perovskite films under electron beam bombardment.

DFT calculations

First-principles calculations based on density functional theory (DFT) were carried out using the Vienna *Ab initio* Simulation Package (VASP) (54). The generalized gradient approximation (GGA) of Perdew-Burke-Ernzerhof (PBE) functional was employed as the exchange-correlation functional (55). We adopt DFT-D3 method for the van der Waals (vdW) correction (56). The plane-wave cutoff energy of 400 eV was used. The energy and force convergence criteria were set to 10^{-5} eV and $0.02 \text{ eV}\cdot\text{\AA}^{-1}$, respectively. In 2D perovskite formation calculations, the binding energies (E_b) of adjacent fragments was defined as (24): $E_B = E_{tot} - E_{fragment1} - E_{fragment2}$, where E_{tot} , $E_{fragment1}$ and $E_{fragment2}$ are the total energies of the entire system, and two fragments cut from the optimized system. The interaction energies (E_{int}) of different ammonium cations (L) with tetragonal MAPbI_3 perovskite surface were calculated as $E_{mol/pvsk} - E_{pvsk} - E_L$, where $E_{mol/pvsk}$, E_{pvsk} and E_L are the total energies of the adsorption system, the perovskite system and LI, respectively. We used a vacuum of 20 \AA to separate two surfaces along the z-direction.

Supplementary Text

Analysis of the energy loss of PSCs

To elucidate the origin of energy loss in PSCs, we started by analyzing the device diode characteristics following our previously established procedure (48). We first obtained the ideality factor n of representative PSCs from the plots of their V_{oc} -incident light intensity dependence (fig. S16). Following these preparations, we break down the energy loss of PSCs based on the following procedures: (1) The Shockley-Queisser limit was calculated from bandgap which we determined from the PL peak wavelength of the perovskite thin film within a complete device stack (Fig. S15b). The bandgaps are found to be around 1.56 eV for different films with small variations. (2) The radiative limit is calculated by using the J_{sc} of the studied devices, the radiative limit of V_{oc} , and assuming an ideal diode behavior ($n = 1$; with series and shunt resistances of $R_{series} = 0$ and $R_{shunt} = \infty$, respectively). The performance losses related to the radiative limit with respect to the Shockley-Queisser limit account for 10.4% for the PEA device and 10.5% for the 345FAn device, mainly stemming from the non-ideal light absorption. (3) The contribution of non-radiative bulk and interface recombination (i.e., non-radiative losses) is further evaluated by calculating the transport limit using the measured V_{oc} and ideality factor, while maintaining the J_{sc} and ideal resistances. Comparing the transport limit with the radiative limit, non-radiative losses are found as 12.7% and 12.1% for PEA and 345FAn devices, respectively. (4) Finally, transport losses are analysed using the measured J - V curve with respect to the transport limit. The PEA device has a higher transport loss (7.4%) than that of 345FAn (6.2%).

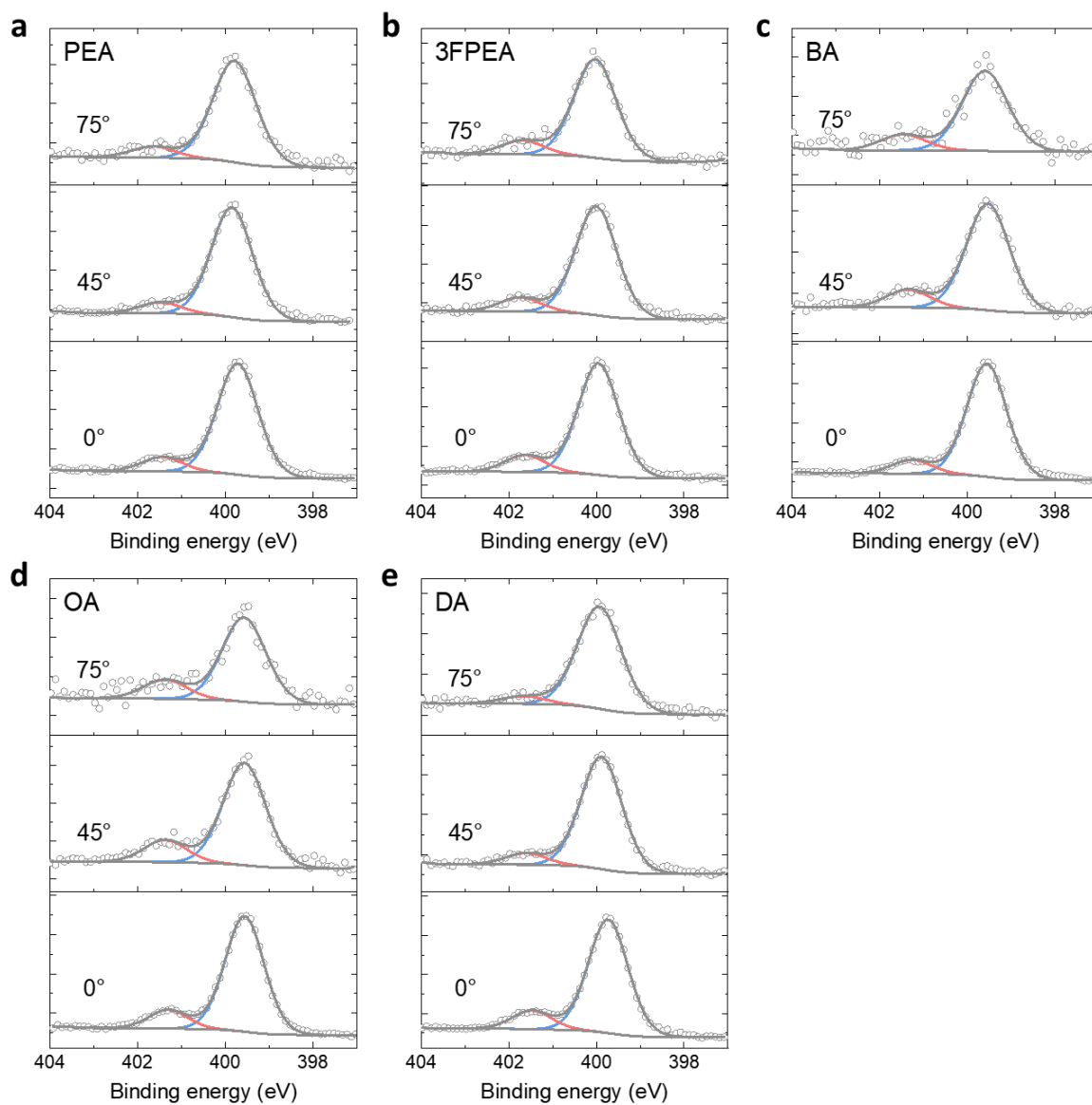


Fig. S1. AR-XPS N 1s region of perovskite films as a function of the electron take-off angles 0°, 45°, and 75°: **a-e**, PEA (**a**), 3FPEA (**b**), BA (**c**), OA (**d**), and DA (**e**) treated films. The pink peak fits the C-N bond and the blue to the N from FA.

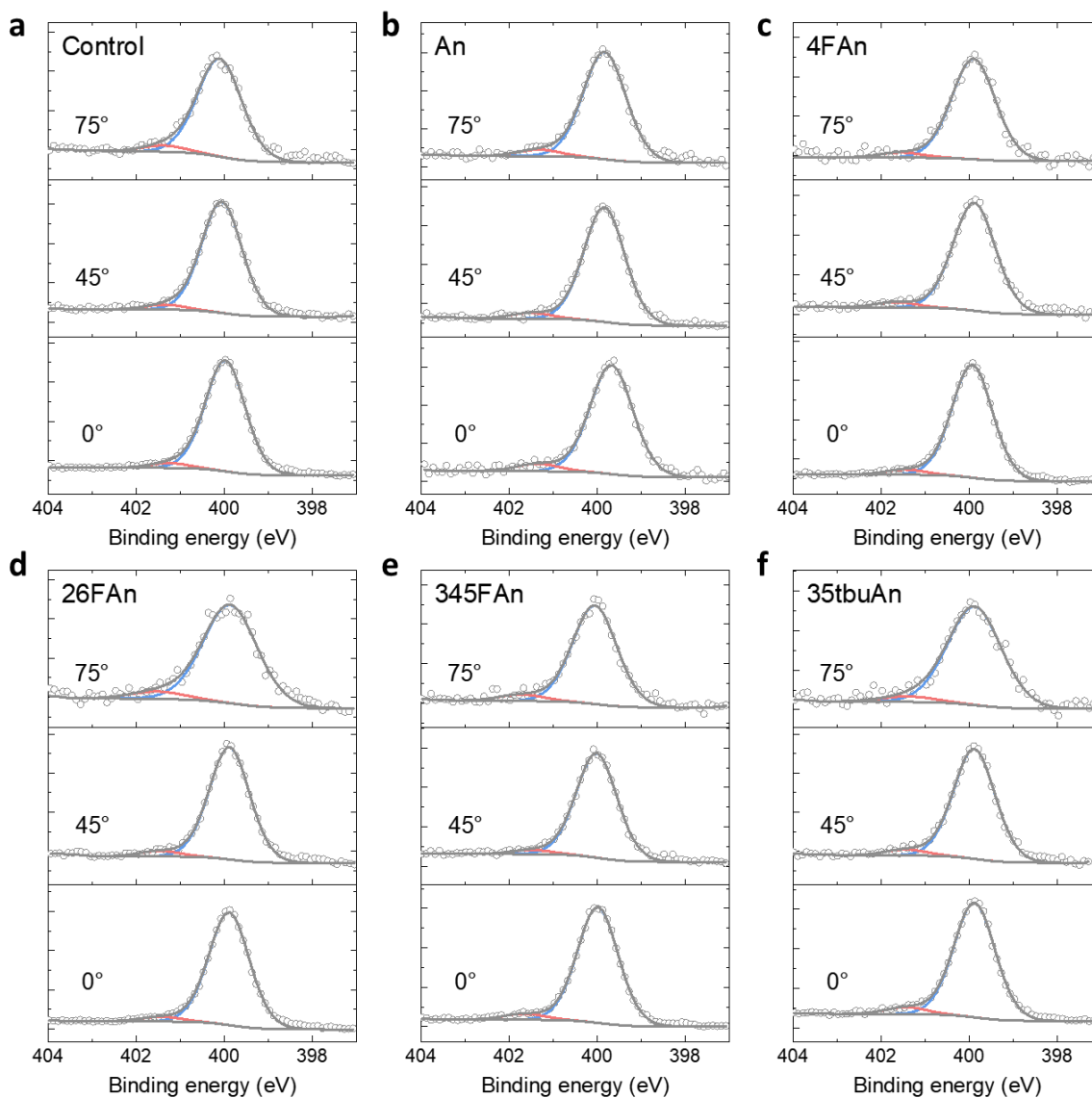


Fig. S2. AR-XPS N 1s region of An and An derivative treated perovskite films as a function of the electron take-off angles 0° , 45° , and 75° : **a-f**, control (**a**), An (**b**), 4FAn (**c**), 26FAn (**d**), 345FAn (**e**), and 35tbuAn (**f**) treated films. The pink peak fits the C-N bond and the blue to the N from FA.

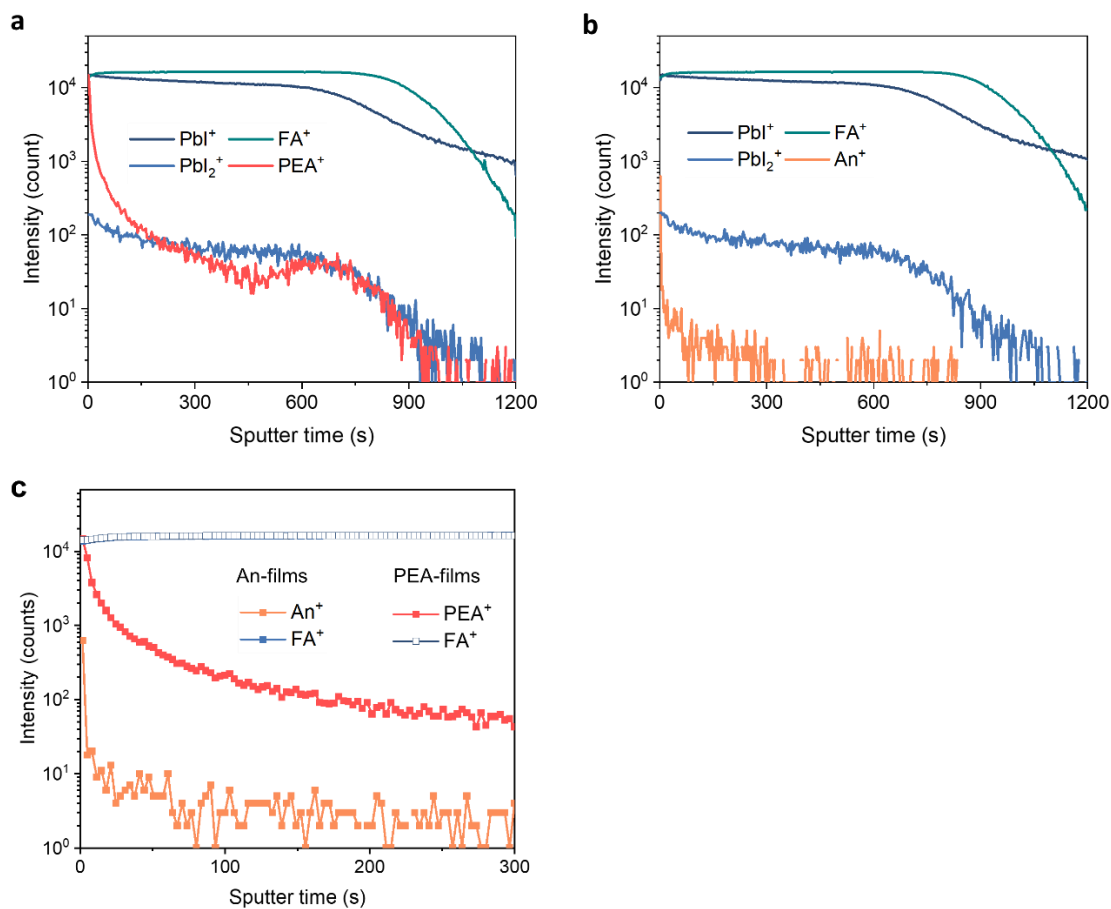


Fig. S3. a-b, TOF-SIMS results of PEA (**a**) and An (**b**) treated perovskite films. An^+ signals are detected near the top film surface. Both PbI_2^+ and FA^+ display a drop in intensities when the sputtering time exceeds 900 s, as the sputtering process reaches the bottom region of the perovskite layer and thus there are fewer perovskite materials available for removal. **c.** Comparison of ligand distribution between PEA and An treated perovskite films. FA^+ signals are plotted for the PEA (dotted points) and An (solid points) samples as the reference. All plots are derived from raw data without normalization.

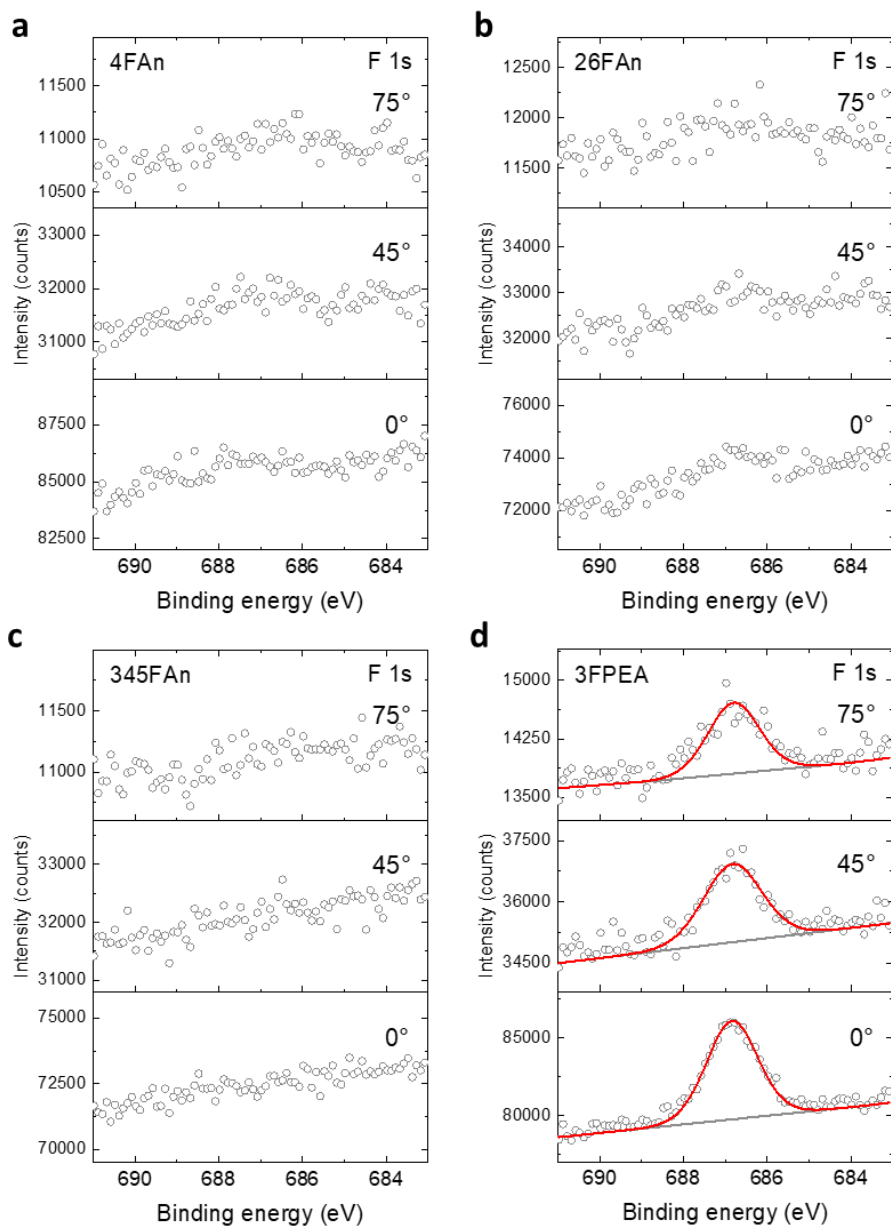


Fig. S4. XPS F 1s region of perovskite films at the electron take-off angle of 0° , 45° , and 75° : **a-c**, 4FAn (**a**), 26FAn (**b**), and 345FAn (**c**)-treated films show negligible C-F signals. **d**, The C-F peak is observed for 3FPEA-treated perovskites at different electron take-off angles. The red peak fits the C-F bond.

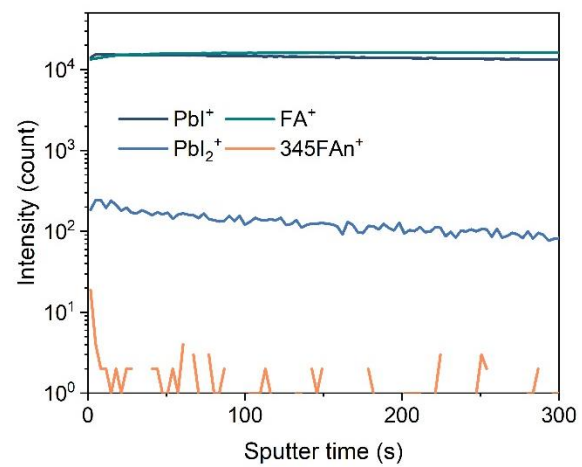


Fig. S5. TOF-SIMS results of 345FAn-treated perovskite films.

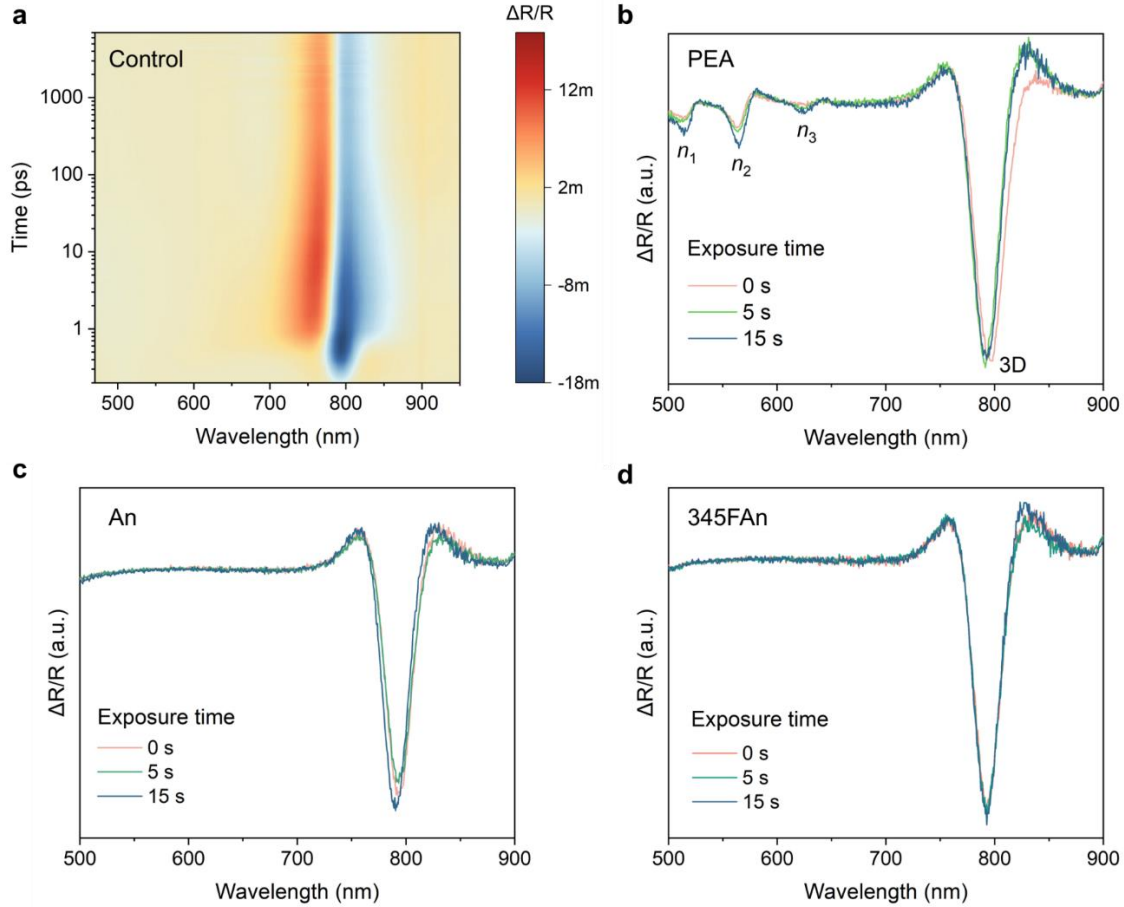


Fig. S6. **a**, Pseudocolour plot of $\Delta R/R$ as a function of incident photon wavelength and delay time for the control perovskite film. **b-c**, TR spectra of the PEA (**b**), An (**c**), and 345FAn (**d**) treated perovskite films at the pump-probe delay time of 410 fs, as a function of the solution exposure time. $n = 1, 2,$ and 3 2D perovskites were found for the PEA-treated films, and their relative proportion to 3D perovskites is increased when the exposure time is prolonged. For An and 345FAn treated films, no 2D phases were detected, irrespective of the exposure time. It is noted that TR spectroscopy is utilized only for examining the phase distribution of quasi-2D perovskites, while photoinactive δ -FAPbI₃ and PbI₂ are detected by GIWAXS.

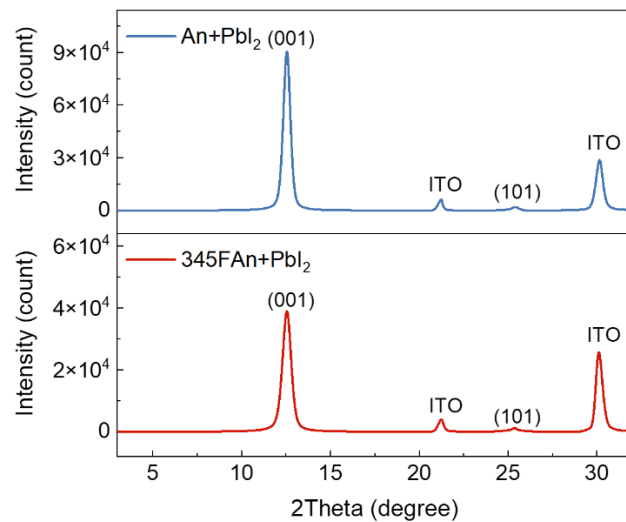


Fig. S7. XRD patterns of mixed An+PbI₂ (top) and 345FAn+PbI₂ (bottom) films. The (001) and (101) diffraction peaks of PbI₂ are observed. There are no 2D-related diffraction peaks for either film.

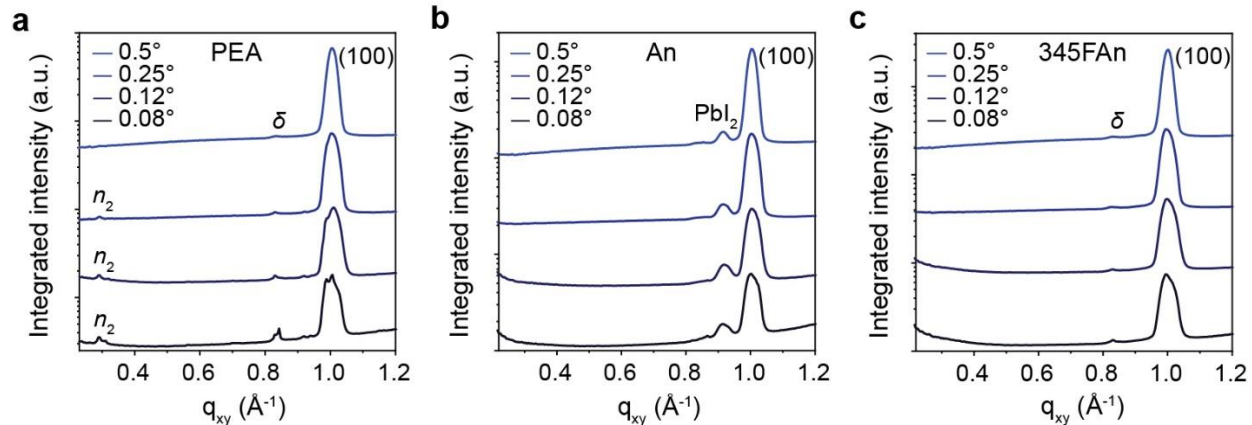


Fig. S8. GIWAXS spectra as a function of incidence angle 0.08° , 0.12° , 0.25° , and 0.5° : **a-b**, Cuts near the q_z axis of GIWAXS measurements for PEA (**a**), An (**b**), and 345FAn (**c**) treated perovskite films. $n = 2$ 2D perovskites (n_2) were observed in the PEA-treated films only at low incidence angles, indicative of the preferable presence of 2D perovskites on the film surface. PbI_2 was observed in the An-treated films due to surface degradation. δ indicates the hexagonal perovskite phase.

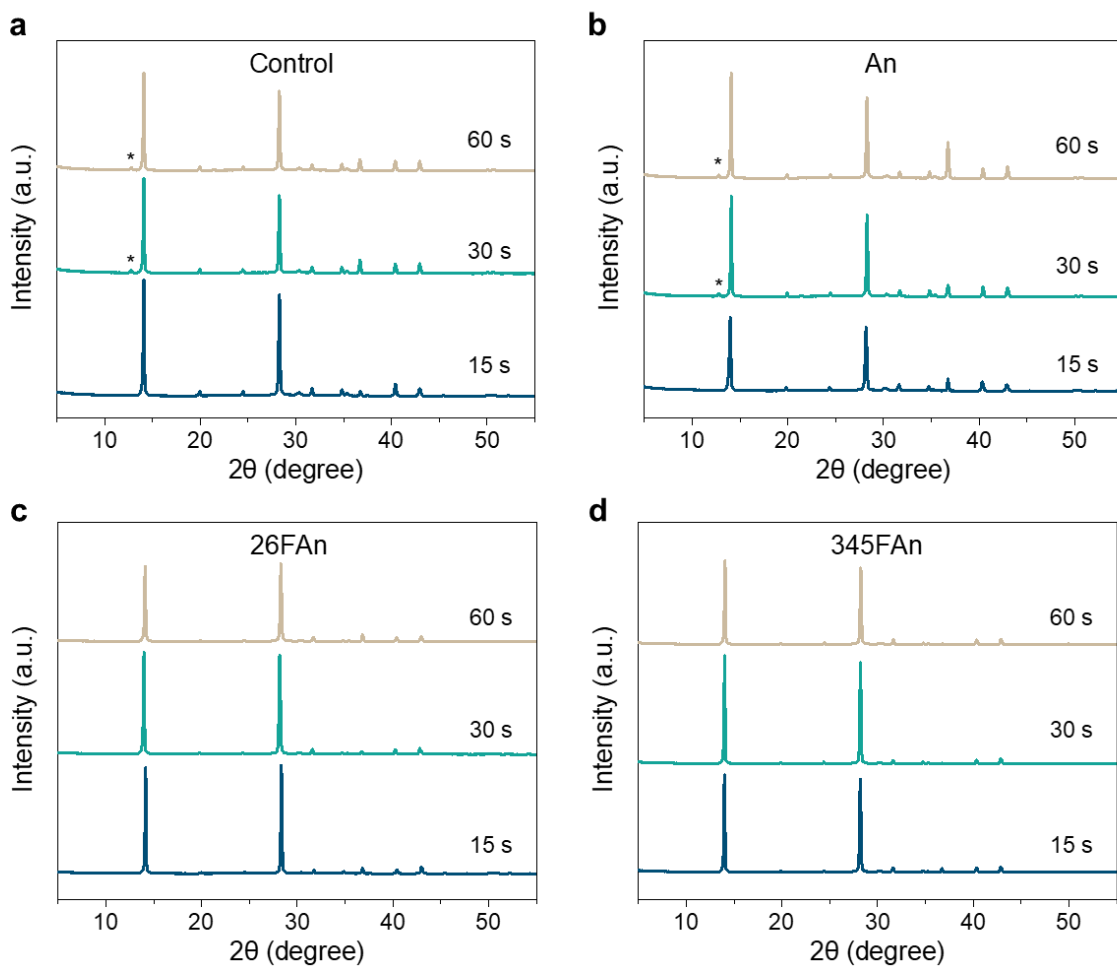


Fig. S9. XRD patterns of perovskite films with varying solution exposure times: **a**, XRD patterns of control perovskite films. The asterisk symbol (*) indicates PbI_2 species. **b-d**, XRD patterns of 4FAn (**b**), 26FAn (**c**), and 345FAn (**d**) treated perovskite films. The generation of PbI_2 during exposure to both pure solvent and An-solution is comparable, which suggests that the decomposition of perovskites is caused by solvents. Films exposed to 26FAn and 345FAn solution exhibited minimal PbI_2 generation, indicating these ammonium ligands can protect perovskites from degradation more efficiently than An.

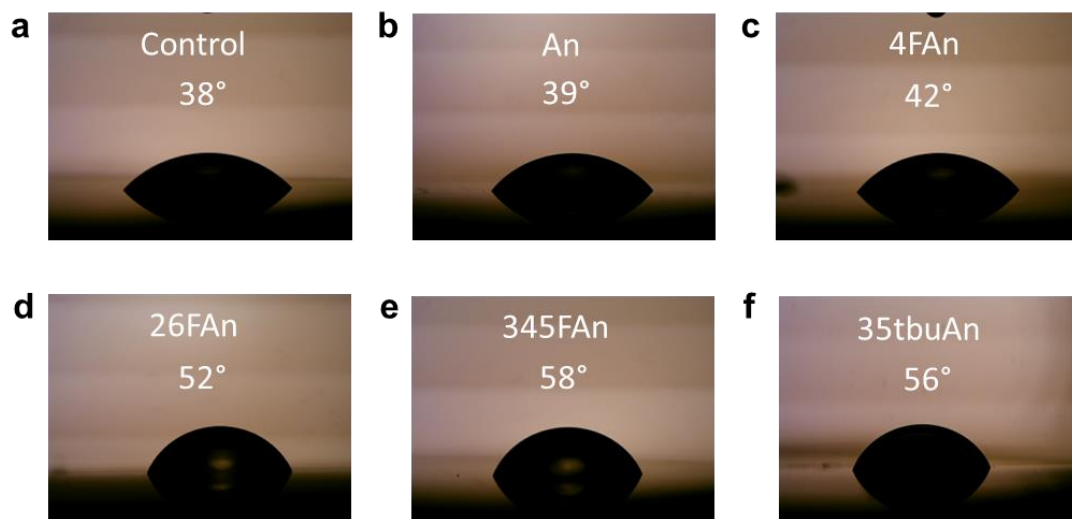


Fig. S10. Contact angle images of control and various ammonium ligand-treated perovskite films: **a-f**, The images of the water droplet for control (**a**) and An (**b**), 4FAn (**c**), 26FAn (**d**), 345FAn (**e**), and 35tbuAn (**f**) treated perovskite films. All images are recorded 2 s after the DI water drop was placed on the surface.

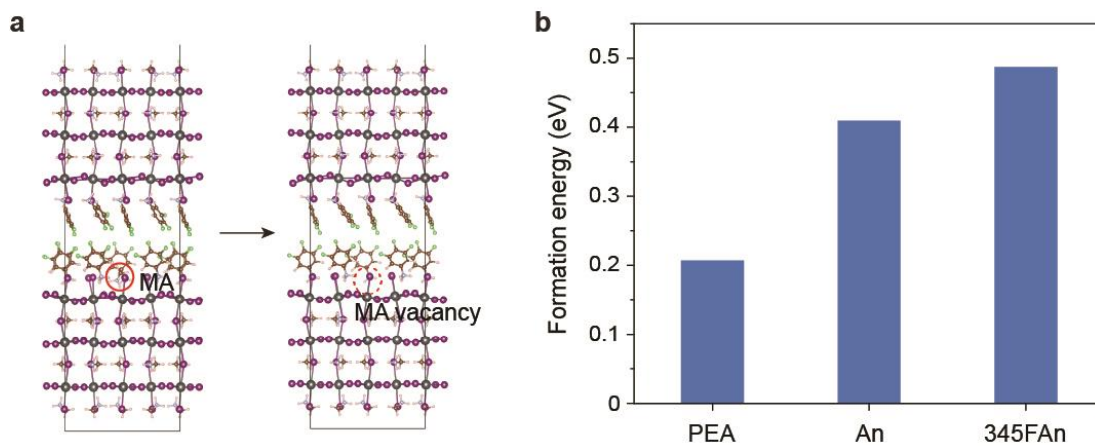


Fig. S11. DFT analysis of MA vacancy formation in various intercalated 2D/3D interfaces: **a**, Computational models used to determine the MA vacancy formation energy in the case of 345FAn intercalation. **b**, MA vacancy formation energies for PEA, An and 345FAn intercalation. Compared to PEA, the removal of MA cations becomes energetically less favorable for An and 345FAn.

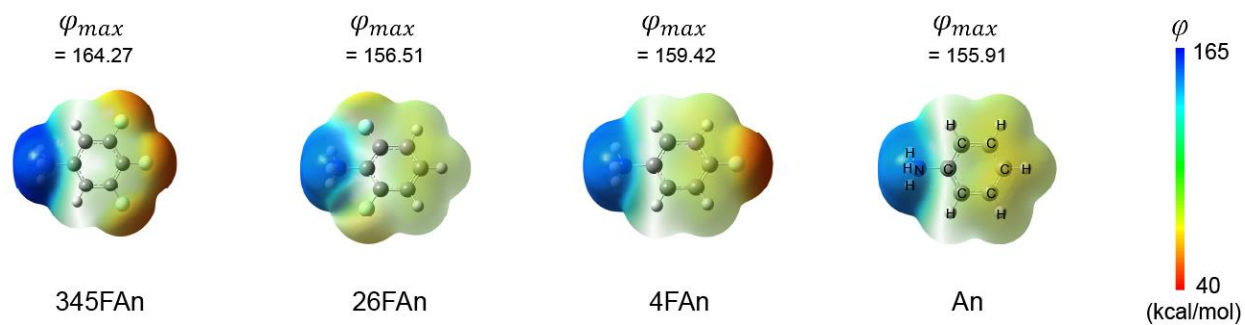


Fig. S12. Gaussian calculated electrostatic potentials (φ) of An and fluorinated An ligands. The right color bar from red to blue marks the increase of electro positivity. The φ_{max} is the maximum electrostatic potential amplitude of a specific ligand (57).

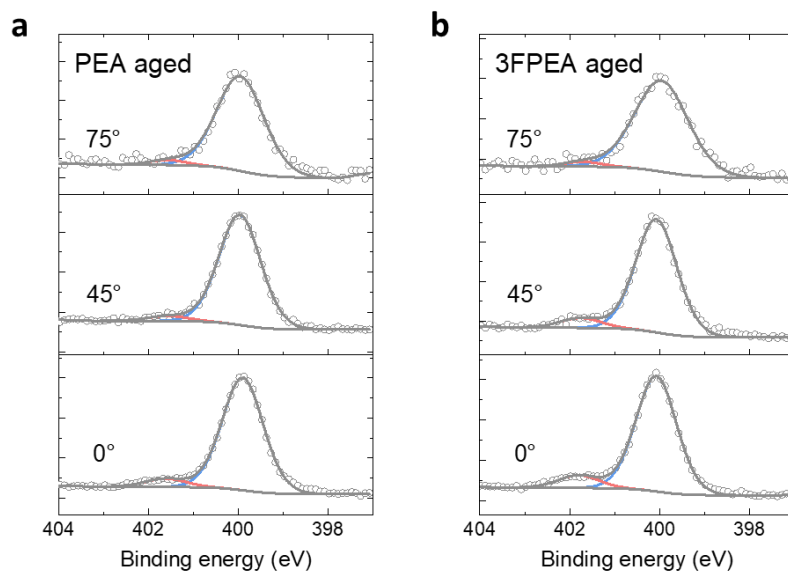


Fig. S13. AR-XPS N 1s region of aged perovskite films as a function of the electron take-off angles 0°, 45°, and 75°: **a,b**, PEA (**a**), and 3FPEA (**b**) treated films measured after 85°C annealing for 2 h. The pink peak fits the C-N bond and the blue to the C=N bond. At a 75° electron take-off angle, the C-N signals diminish significantly in comparison to the fresh sample for both films, suggesting decreased surface presence due to ligand penetration.

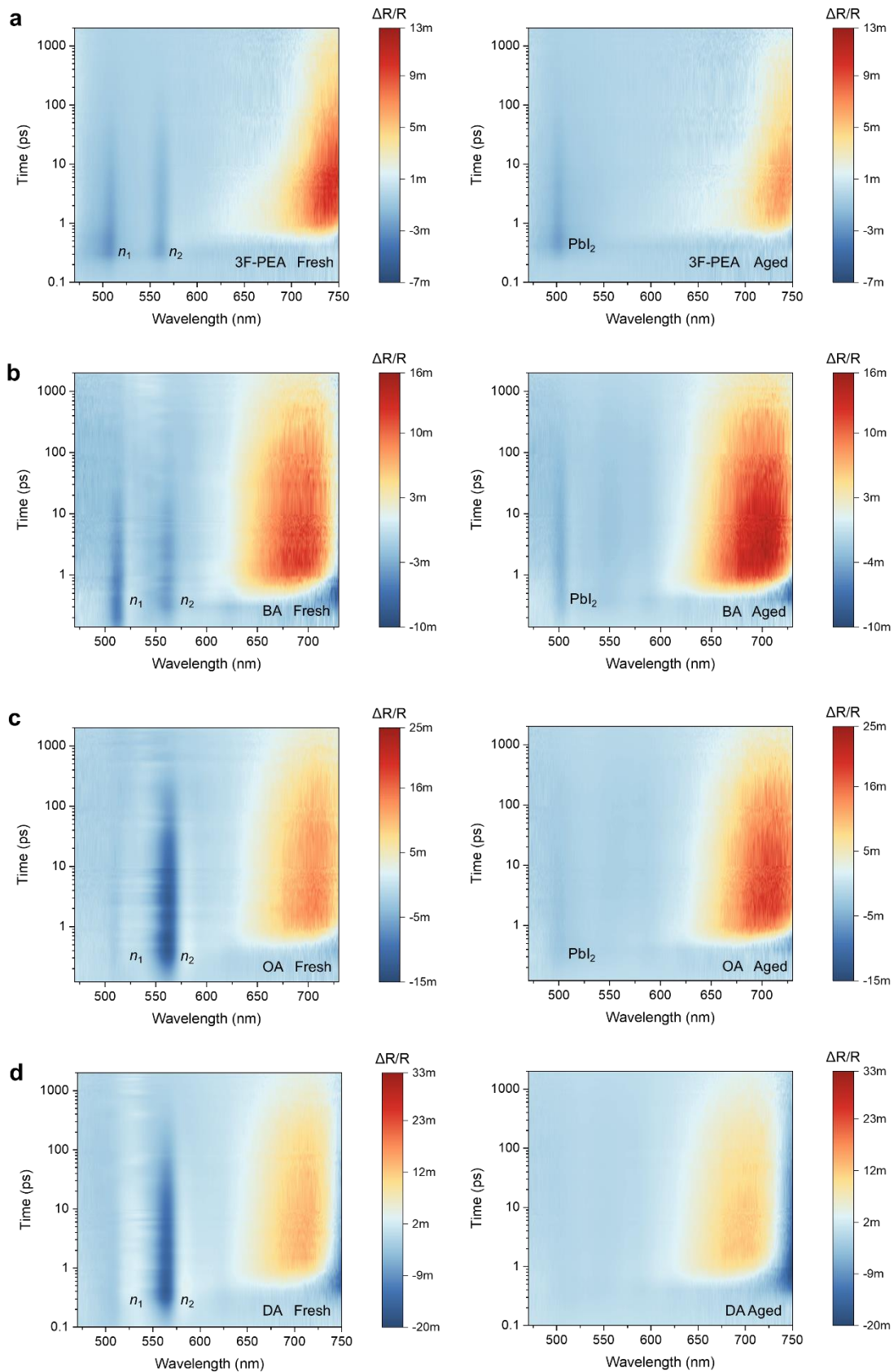


Fig. S14. Phase stability of penetrating ammonium ligand-treated perovskite films: **a-d**, Pseudocolor representation of the transient reflectance spectra for 3FPEA (**a**), BA (**b**), OA (**c**), and DA (**d**) treated perovskite films before (fresh) and after (aged) thermal aging at 85°C for 2 h. All 2D phases disappeared from the film surfaces after thermal aging.

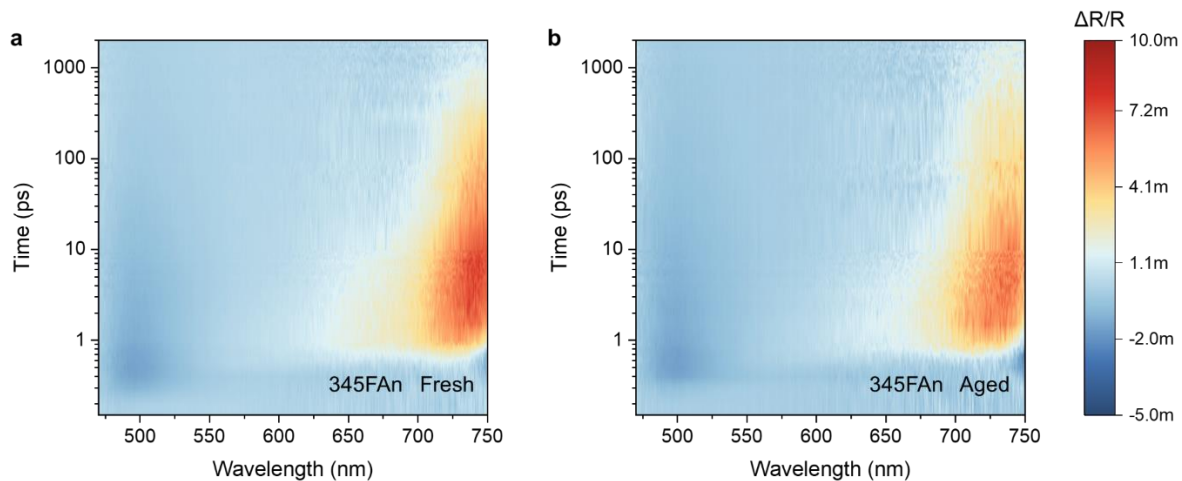


Fig. S15. Phase stability of 345FAn treated films at elevated temperatures: **a,b**, Pseudocolor representation of the transient reflectance spectra for the 345FAn treated perovskite film before **(a)** and after **(b)** thermal aging at 85°C for 2 h. No apparent phase change was observed after thermal aging.

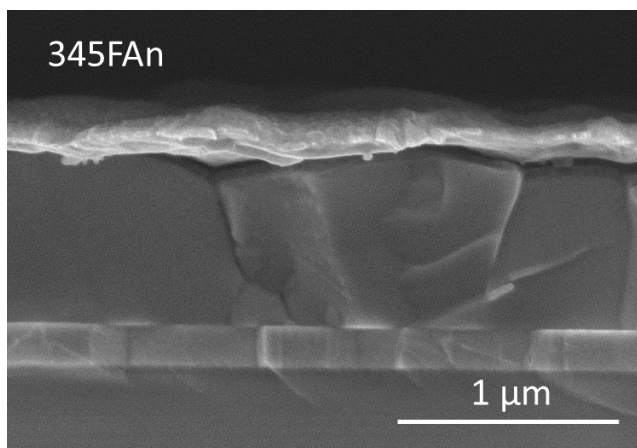


Fig. S16. Cross-sectional SEM image of 345FAn treated inverted PSCs. Scale bar = 1 μm.

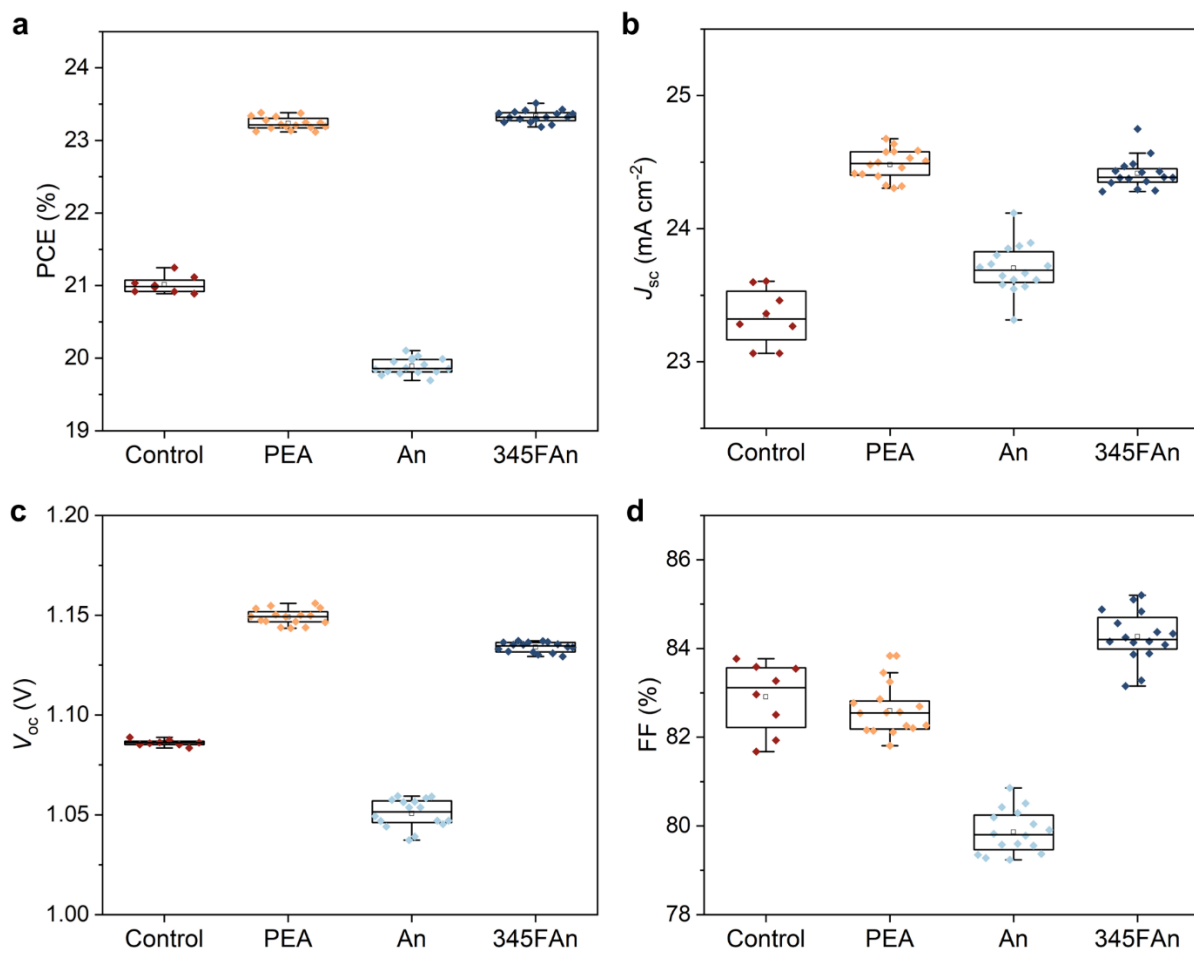


Fig. S17. Performance of control and treated PSCs: **a-d**, PV parameters, including PCE (**a**), J_{sc} (**b**), V_{oc} (**c**), and FF (**d**), of control devices (8 devices) and treated PSCs (16 devices for each type).

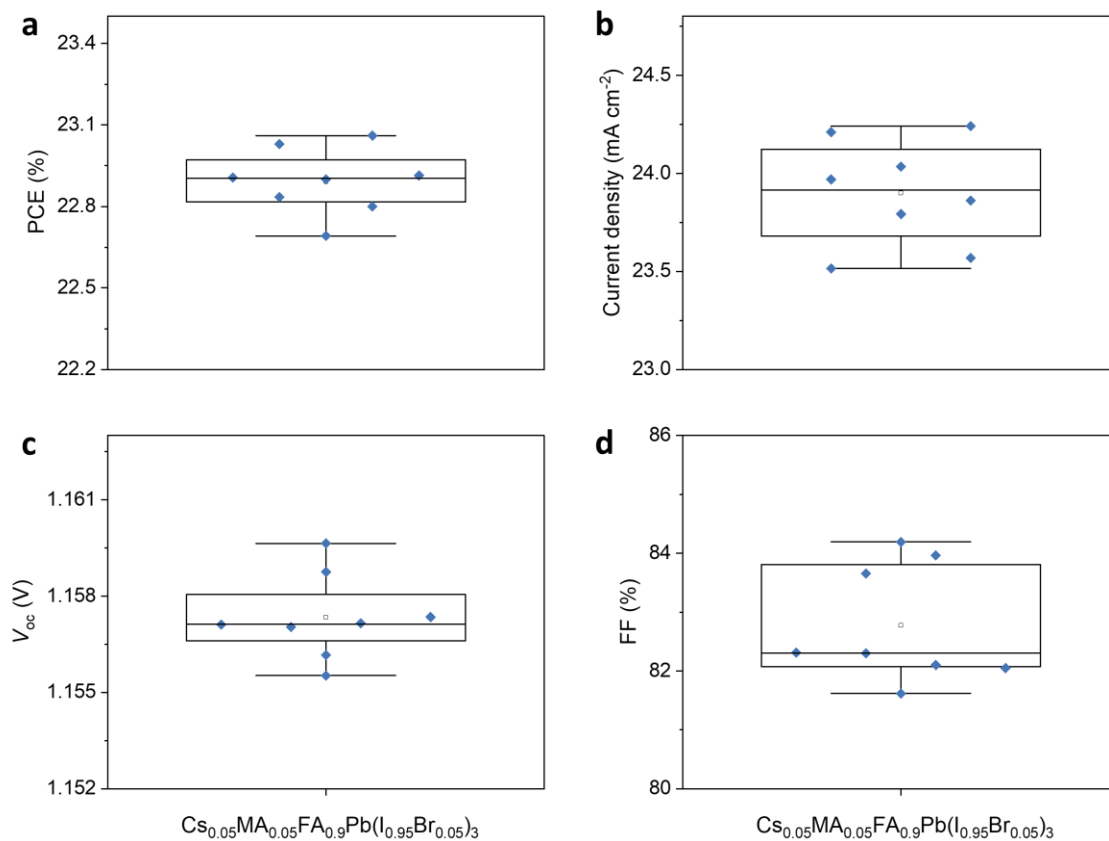


Fig. S18. PV parameters of treated $\text{Cs}_{0.05}\text{MA}_{0.05}\text{FA}_{0.9}\text{Pb}(\text{I}_{0.95}\text{Br}_{0.05})_3$ devices: **a-d**, PCE (**a**), J_{sc} (**b**), V_{oc} (**c**), and FF (**d**) of 345FAn-treated devices (8 devices). Statistical distribution is represented in box-and-whisker plots (line within the box: median, box limit: 25th and 75th percentiles, whiskers: outliers).

University of Toronto

1-J Perovskite Cell

Device ID: SMP 1-4

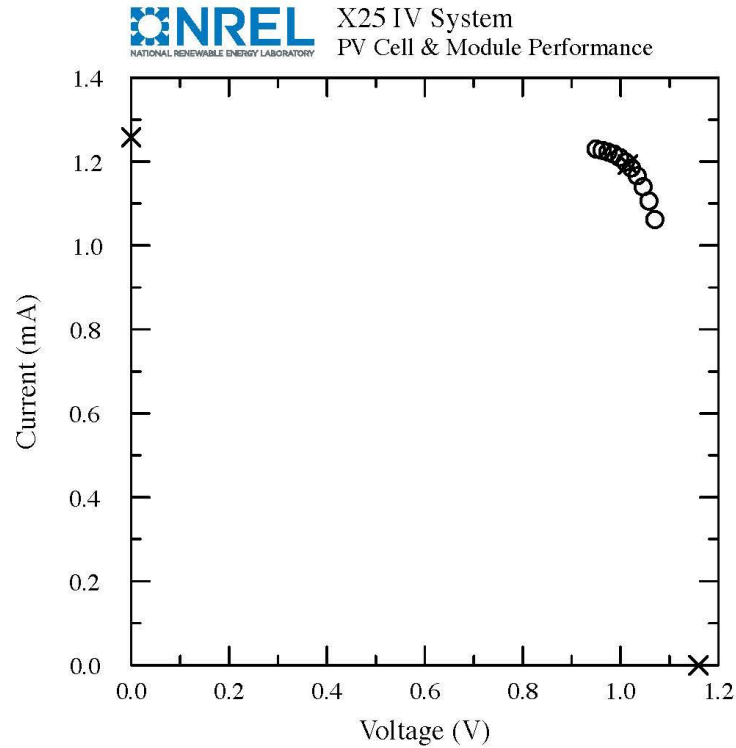
Device temperature: 25.0 ± 0.2 °C

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Device area: $0.05031 \text{ cm}^2 \pm 0.5\%$

Spectrum: ASTM G173 global

Irradiance: 1000.0 W/m^2



$$V_{oc} = 1.1595 \pm 0.0018 \text{ V}$$

$$I_{max} = 1.1935 \pm 0.0098 \text{ mA}$$

$$I_{sc} = 1.259 \pm 0.010 \text{ mA}$$

$$V_{max} = 1.0154 \pm 0.0023 \text{ V}$$

$$J_{sc} = 25.02 \pm 0.31 \text{ mA/cm}^2$$

$$P_{max} = 1.212 \pm 0.010 \text{ mW}$$

$$\text{Fill Factor} = (83.05 \pm 0.82) \%$$

$$\text{Efficiency} = (24.09 \pm 0.30) \%$$

Asymptotic IV

Elapsed time: 705 s.

Fig. S19. Certified results of the inverted PSC with 345FAn passivation.

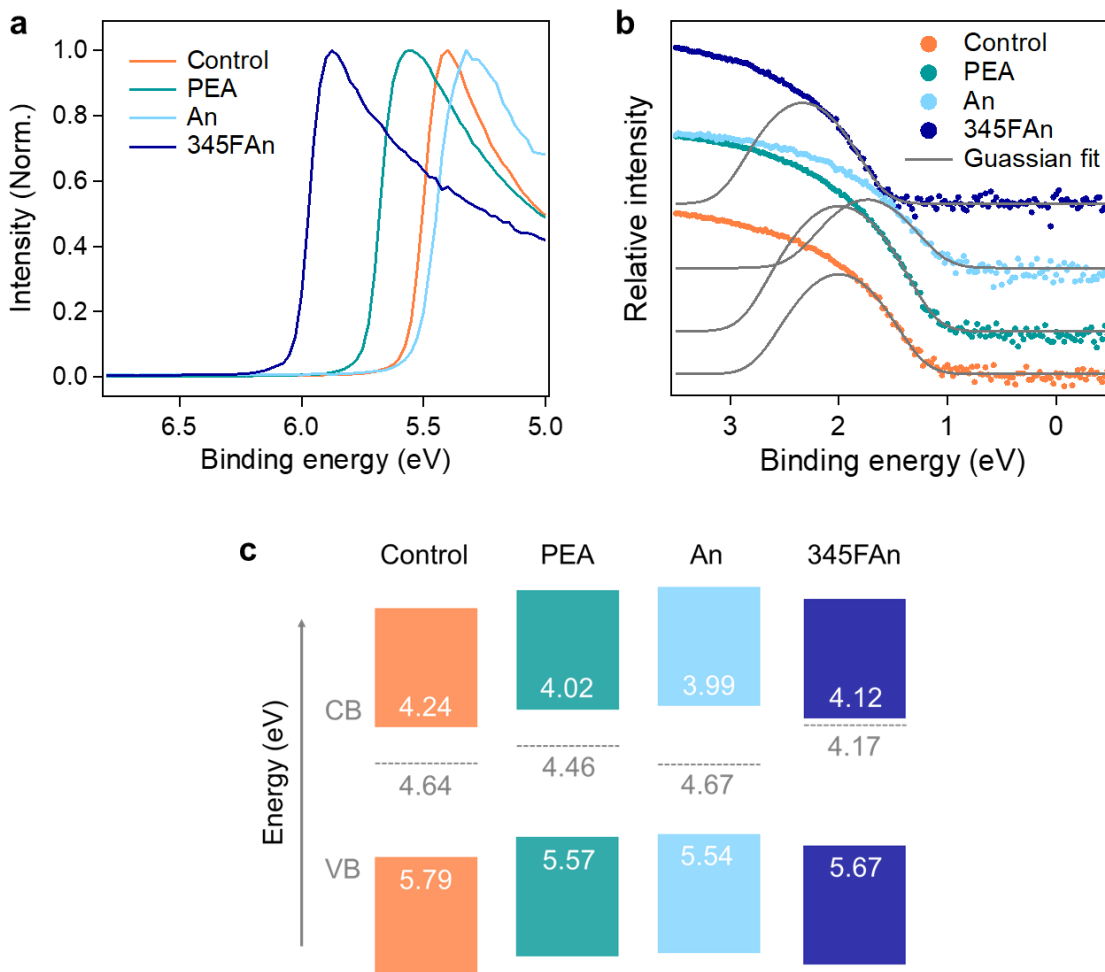


Fig. S20. UPS spectra and energy level schematic: **a,b**, Secondary electron cut-off region (**a**), and valence band onset region (**b**) plotted on a relative logarithmic scale of control and ammonium ligand treated films. The x-axis energy scale is with respect to the Fermi energy. Gaussian fit (grey solid line) was used to determine the valence band (58). **c**, Energy diagram comparing the alignment between the control and ammonium ligand treated films. The dashed lines indicate work functions. 345FAn induces the n-type perovskite film.

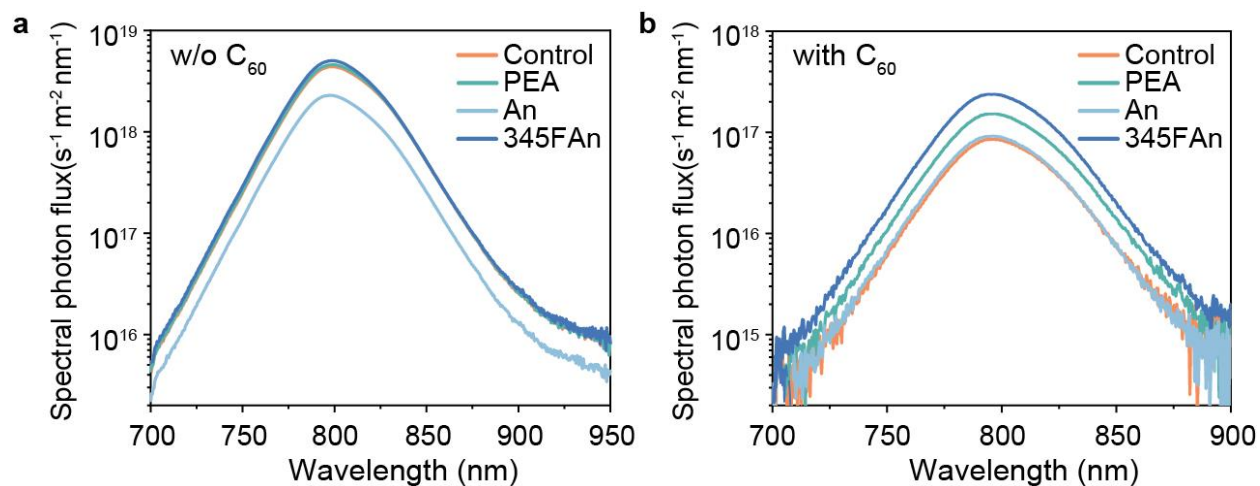


Fig. S21. a-b, Absolute intensity PL spectra of perovskite thin films on glass/ITO/2PACz without (a) or with (b) a 30 nm-thick C_{60} overlayer. The corresponding PLQY and QFLS values are summarized in Table S3.

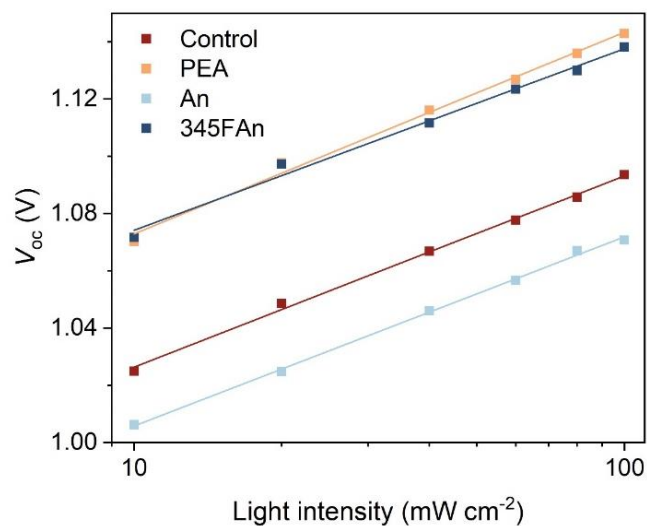


Fig. S22. V_{oc} -light intensity dependence of PSCs. The values of the ideality factor for control, PEA, An, and 345FAn devices are 1.13, 1.19, 1.12, and 1.07, respectively. It is noted that no direct correlation between ideality factor and device performance is found herein. This can be explained by recent findings: Although non-radiative bulk recombination leads to a higher ideality factor, surface and interface recombination can lead to a lower one (59, 60). In addition, the ideality factor in perovskites solar cells can also be critically affected by the ionic nature of the absorber layer (61).

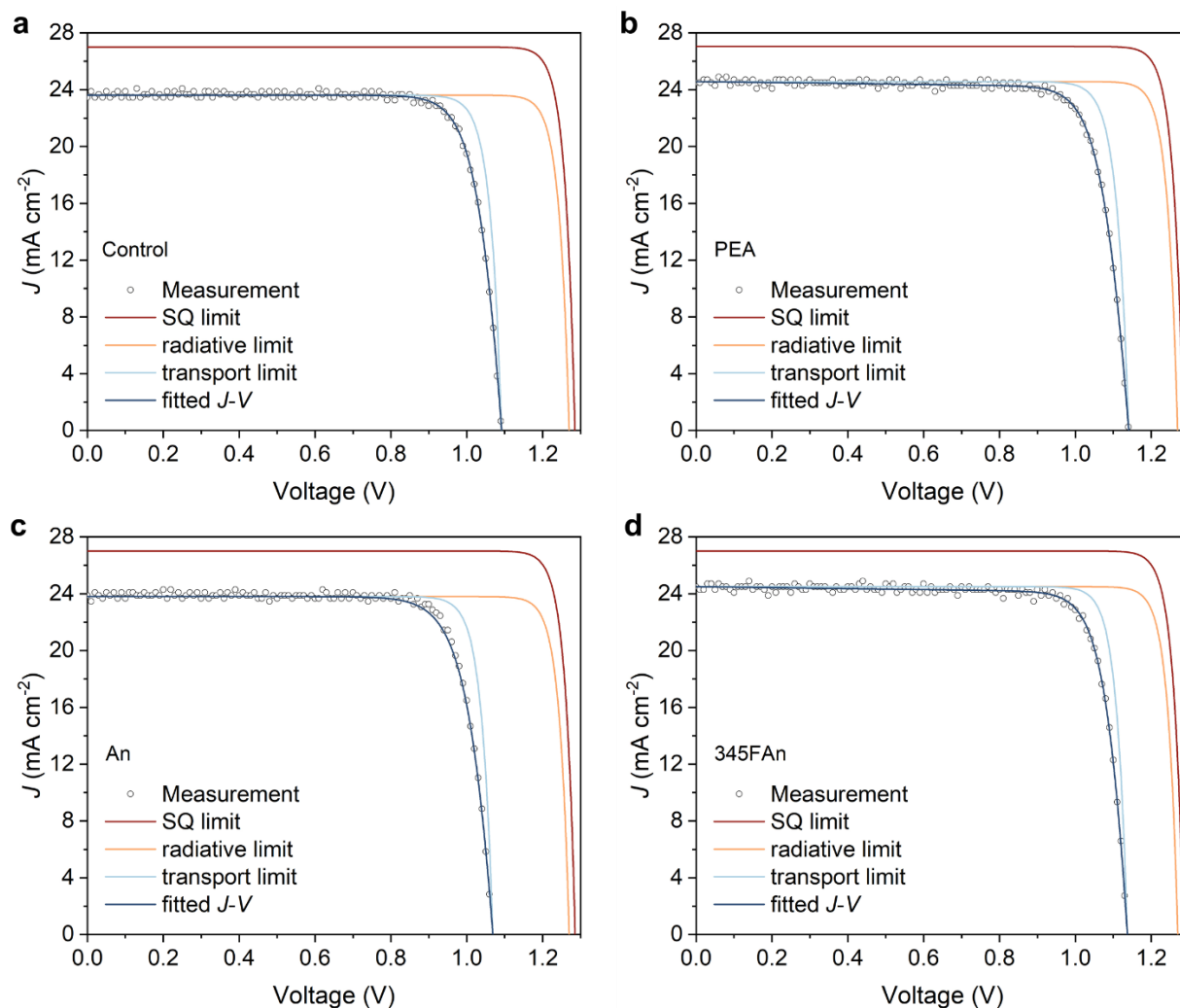


Fig. S23. a-d, J - V characteristics of control (a) and PEA (b), An (c), and 345FAn (d) treated PSCs. The details behind the shown J - V curves can be found in supplementary text. Losses due to non-radiative recombination appear in V_{oc} and FF, transport losses apparent between the transport limit J - V curve and the measured J - V curve additionally lower the FF.

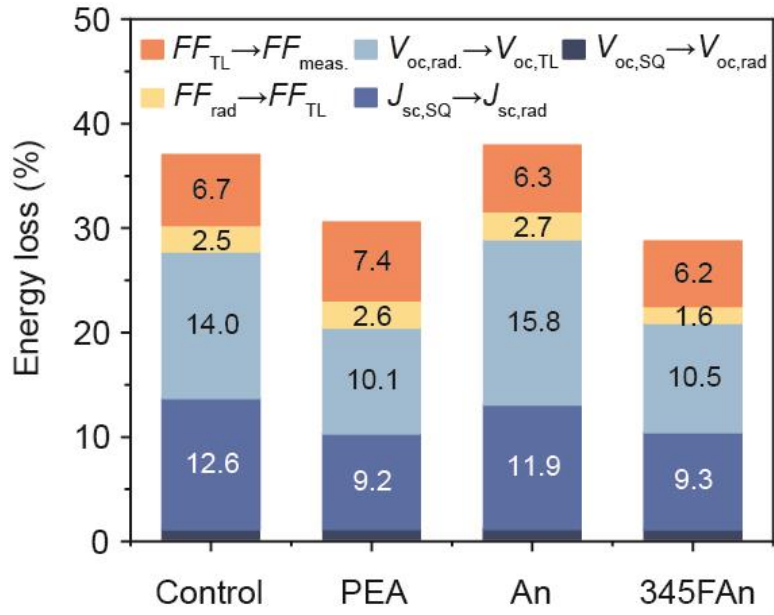


Fig. S24. Breakdown of energy loss in PSCs derived from the J - V fits.

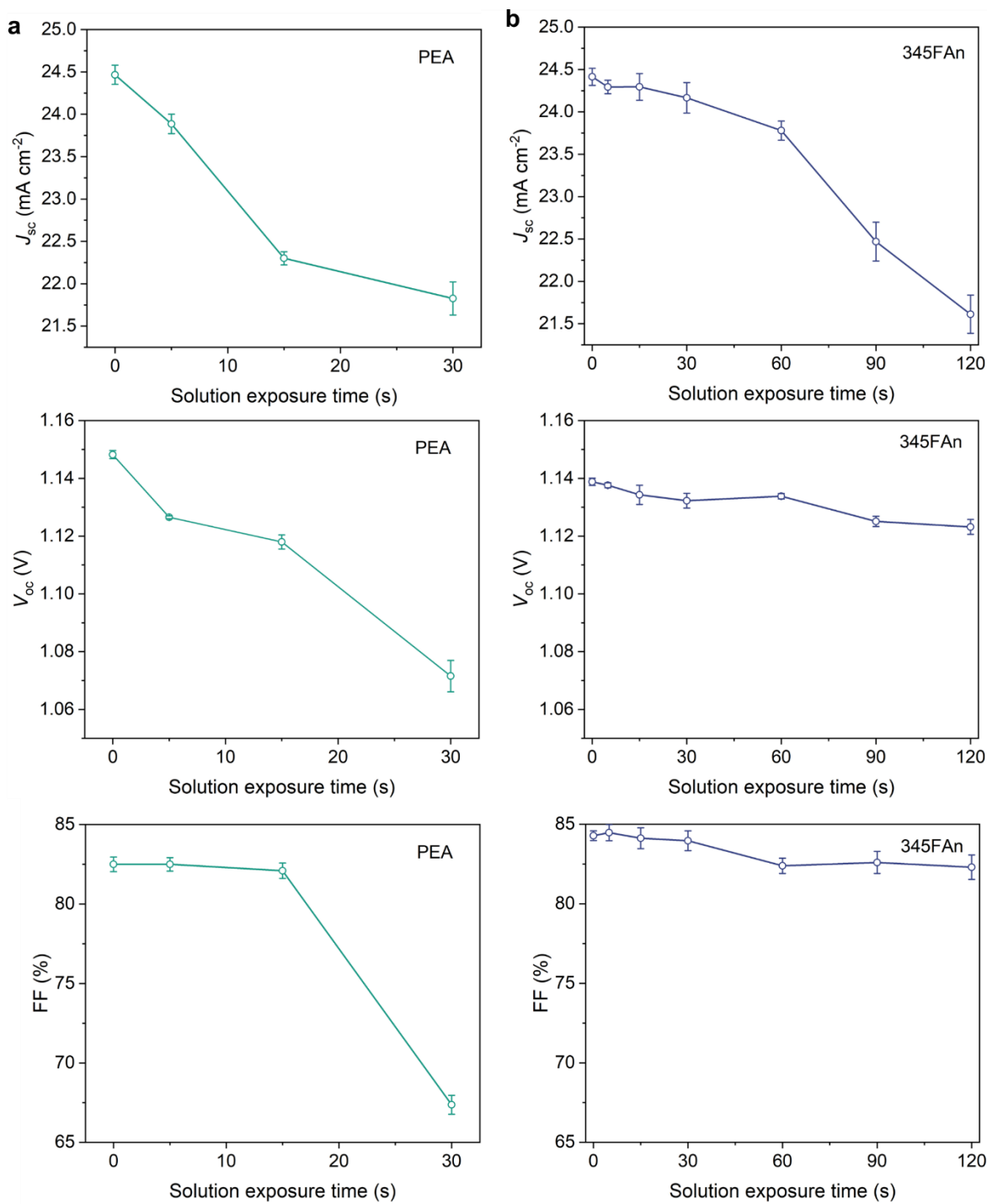


Fig. S25. PV performance of PEA and 345FAn treated PSCs as a function of solution exposure times: **a,b**, PV parameters, including J_{sc} , V_{oc} , and FF, of PEA (**a**) and 345FAn (**b**) treated devices with different solution exposure times (8 devices for each condition). Data are presented as mean values \pm standard deviation.

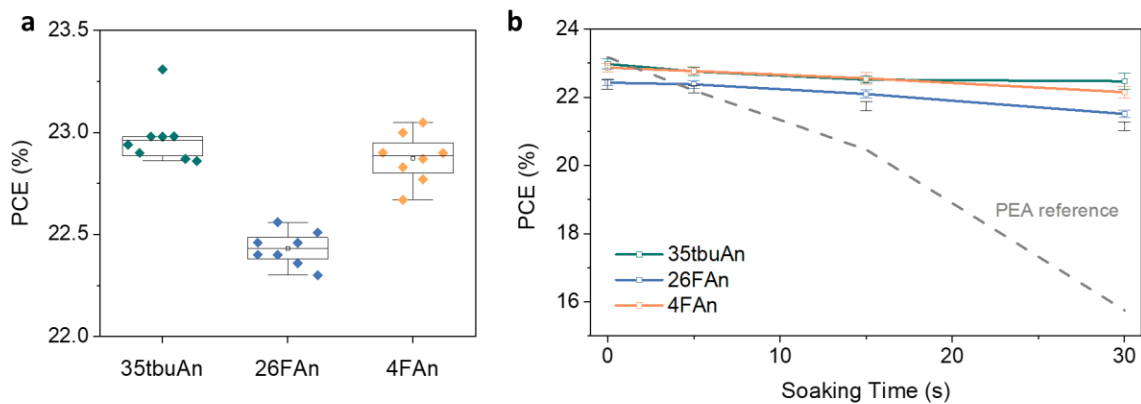


Fig. S26. Device performance of PSCs with different An-derivative passivation: **a**, PCE statistics for 35tbuAn, 26FAn, and 4FAn-treated PSCs (8 devices for each type). **b**, PCE evolution of ligand-treated devices as a function of solution exposure time (8 devices for each condition). Data are presented as mean values \pm standard deviation. The grey dash line is the PCE evolution of PEA-treated devices.

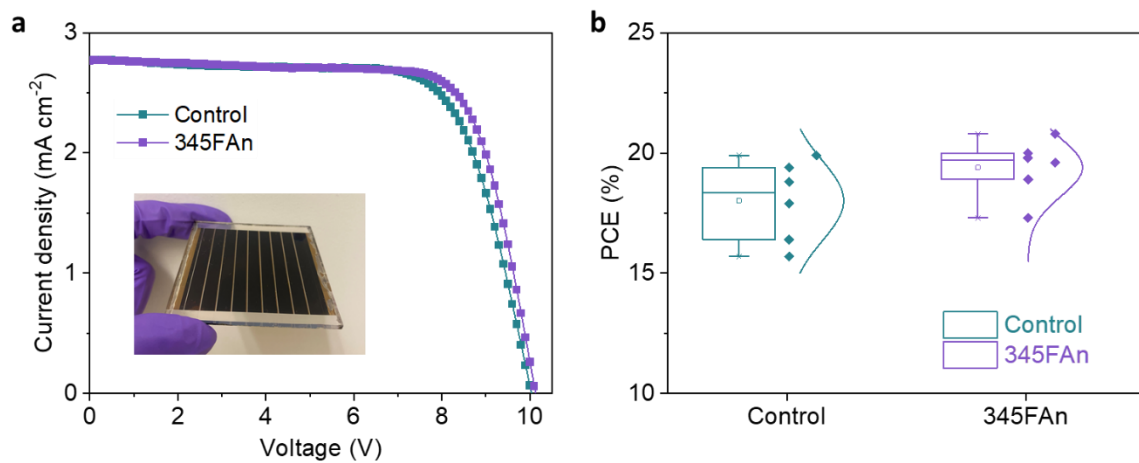


Fig. S27. Photovoltaic performance of control and 345FAn treated perovskite solar modules: **a,b**, *J-V* curves (**a**) and PCE statistics (**b**) of control and 345FAn treated perovskite solar module with an active area of 22 cm². Inset: Photograph of a representative perovskite solar module.

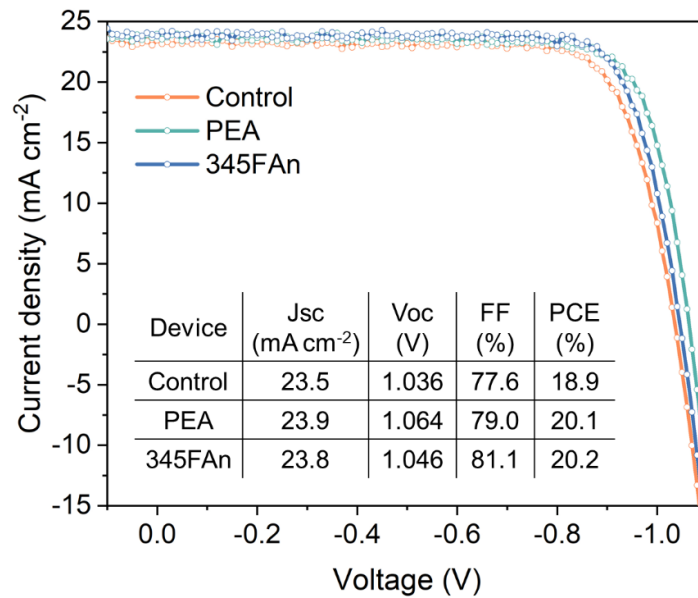


Fig. S28. *J-V* curves and figures of merit for devices used in stability testing. The device architecture is ITO/2PACz/Perovskite/C₆₀/ALD-SnO_x/Ag and the perovskite composition is Cs_{0.05}MA_{0.05}FA_{0.9}Pb(I_{0.95}Br_{0.05})₃.

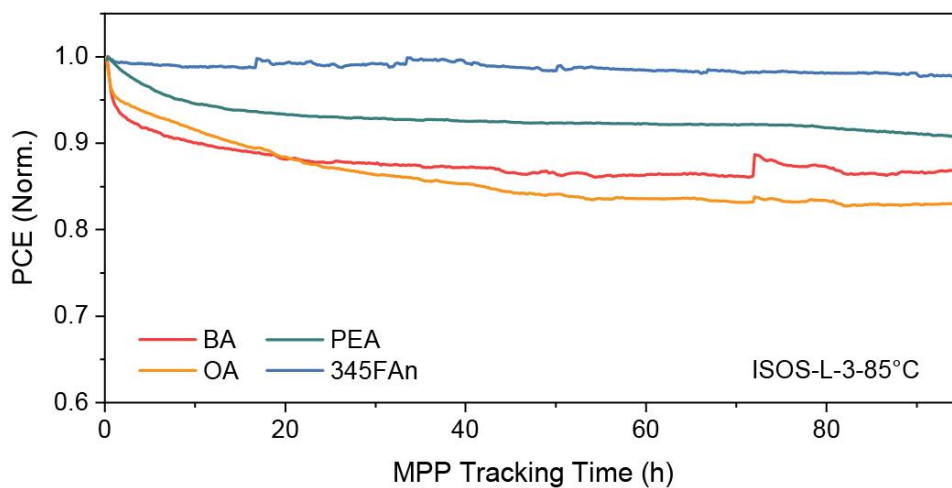


Fig. S29. MPP tracking of encapsulated BA and OA devices at 85°C with a relative humidity of ~50% under 0.8-sun illumination. PEA and 345FAn results, as presented in Fig. 5E, are included for reference.

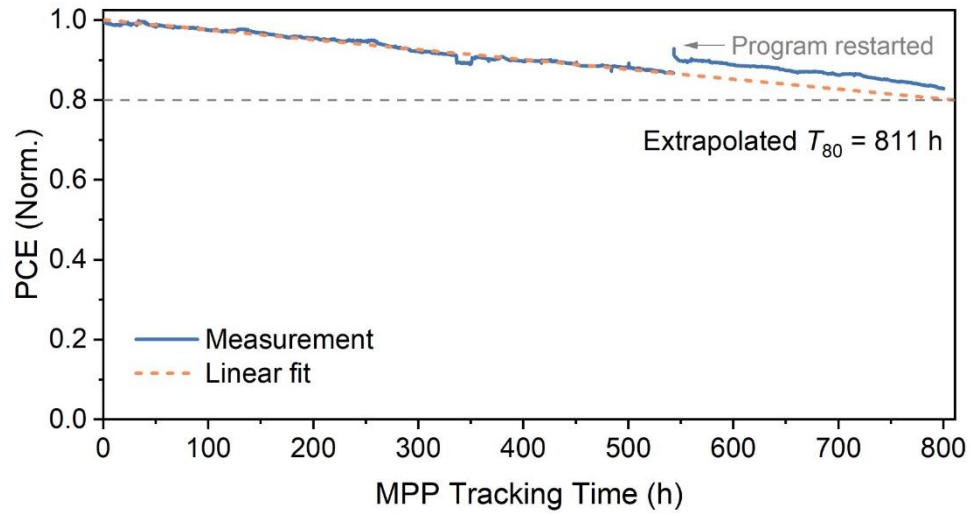


Fig. S30. Linear extrapolation of stability testing. Based on the initial 500 h stability data, we estimate the T_{80} lifetime to be ~810 h for the 345FAn-treated PSC using linear extrapolation.

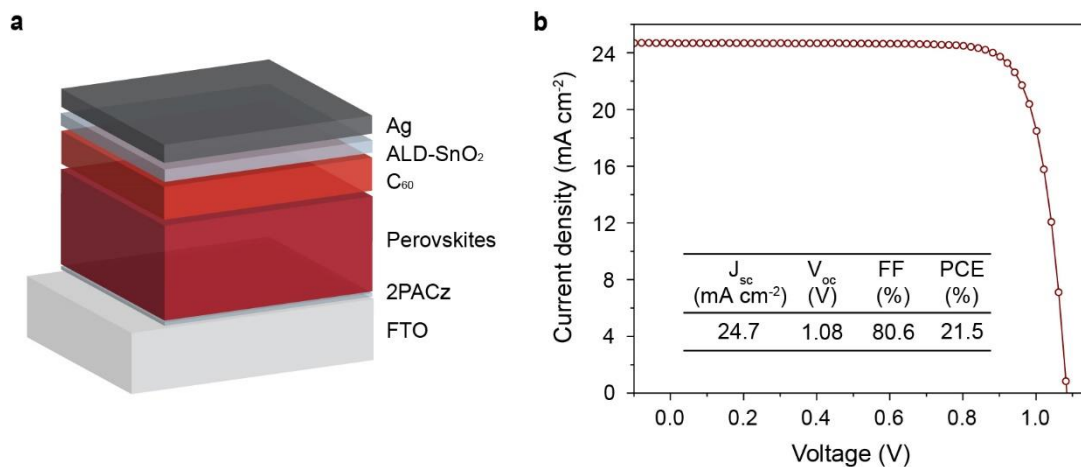


Fig. S31. a,b, The device architecture (**a**), J - V curve, and figures of merit (**b**) for the FTO device used in stability testing. The perovskite composition is Cs_{0.05}MA_{0.05}FA_{0.9}Pb(I_{0.95}Br_{0.05})₃. The J - V curve was measured under 1-sun-equivalent white LED illumination at room temperature.

Table S1. XPS peak position and area for control and ammonium-ligand-treated perovskite films at $\alpha = 0^\circ, 45^\circ,$ and 75° electron take-off angles

Films	Take-off angle ($^\circ$)	C-N peak position (eV)	C-N peak area	FA N peak position (eV)	FA N peak area	C-N to FA N ratio
Control	0	401.3	0.80	400.0	18.0	0.04
	45	401.3	0.74	400.0	16.5	0.04
	75	401.4	0.91	400.1	14.2	0.06
PEA	0	401.4	1.82	399.7	14.0	0.13
	45	401.5	1.31	399.8	13.1	0.10
	75	401.6	1.25	399.8	11.4	0.11
3FPEA	0	401.6	2.14	399.9	14.2	0.15
	45	401.7	1.72	400.0	13.3	0.13
	75	401.7	1.54	400.0	10.9	0.14
BA	0	401.3	1.56	399.6	12.7	0.12
	45	401.4	1.78	399.5	10.5	0.17
	75	401.5	1.80	399.6	9.06	0.20
OA	0	401.3	2.31	399.6	14.2	0.16
	45	401.4	2.67	399.6	12.2	0.22
	75	401.4	2.38	399.6	10.5	0.23
DA	0	401.5	2.31	399.7	14.1	0.16
	45	401.6	1.58	399.9	15.2	0.10
	75	401.6	1.02	399.9	13.6	0.08
An	0	401.4	0.86	399.7	12.5	0.06
	45	401.5	0.78	399.8	15.2	0.05
	75	401.3	0.81	399.8	13.2	0.06
4FAn	0	401.5	0.57	399.9	12.7	0.04
	45	401.6	0.54	399.9	10.9	0.05
	75	401.5	0.40	399.9	7.83	0.05
26FAn	0	401.4	0.66	399.9	15.6	0.04
	45	401.4	0.64	399.9	12.8	0.05
	75	401.5	0.76	399.9	10.1	0.07
345FAn	0	401.6	0.83	400.0	16.1	0.05
	45	401.5	0.57	400.0	14.1	0.04
	75	401.7	0.77	400.0	11.7	0.06
35tbuAn	0	401.4	0.90	399.9	14.7	0.06
	45	401.4	0.68	399.9	12.4	0.05
	75	401.4	0.16	399.9	3.2	0.05

Table S2. Summary of quasi-steady-state (QSS) certified PV parameters of > 21% PCE inverted PSCs

V_{oc} (V)	J_{sc} (mA cm ⁻²)	FF (%)	PCE	Ref.
1.1595	25.02	83.05	24.09% (NREL)	This work
1.1607	25.44	81.48	24.05% (NREL)	Q. Jiang, Nature (2022) (45)
1.1505	24.90	83.46	23.91% (NREL)	H. Chen, Nat. Photonics (2022) (23)
1.1687	22.89	84.55	22.62% (NREL)	S. Chen, Sci. Adv (2021) (62)
1.1429	23.84	82.0	22.34% (Newport)	X. Zheng, Nat. Energy (2020) (63)

Table S3. Summary of PL peak position, PLQY, $V_{oc,rad}$, and QFLS for the perovskite thin films with or without the C₆₀ overlayer

Films	Overlayer	PL peak position (nm)	PLQY (%)	$V_{oc,rad}$ (V)	QFLS (eV)
Control	None	799	13.4	1.265	1.213
	C ₆₀	796	0.26	1.269	1.117
PEA	None	798	13.9	1.265	1.214
	C ₆₀	797	0.47	1.270	1.132
An	None	797	7.0	1.266	1.198
	C ₆₀	796	0.28	1.270	1.119
345FAn	None	799	15.0	1.266	1.217
	C ₆₀	795	0.73	1.271	1.144

Table S4. Summary of reported device operational stability based on ISOS-L-3 protocols.

Light source	T	Environment	Surface passivation	PCE @high-T	Lifetime	Ref.
White LED	85°C	~50% RH	345FAn	19.9% (85°C)	T₈₅ = 1560 h	This work
White LED	65°C	~50% RH	3FPEA 2D/3D	N.A.	T ₉₂ = 500 h	H. Chen, Nat. Photonics (2022) (23)
Metal-halide lamp	85°C	~65% RH	Cs ₂ PbI ₂ Cl ₂	~16.5% (85°C)	T ₈₅ = 4000 h	X. Zhao, Science (2022) (12)
Xenon lamp	85°C	~50% RH	None	~14.2% (85°C)	T ₉₅ = 1200 h (Post 15% burn-in)	Y-H. Lin, Science (2020) (11)
Plasma lamp	65°C	~60% RH	PbSO ₄	~19.5% (65°C)	T _{96.8} = 1200 h	S. Yang, Science (2019) (18)

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